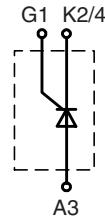


Single Thyristor Module

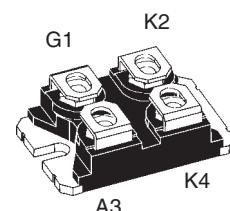
I_{TRMS} = 234 A
V_{RRM} = 1200-1600 V
I_{TAV} = 149 A

Preliminary data

V _{RSM}	V _{RRM}	Type
V _{DSM}	V _{DRM}	
V	V	
1200	1200	MCO 150-12io1
1600	1600	MCO 150-16io1



miniBLOC, SOT-227 B



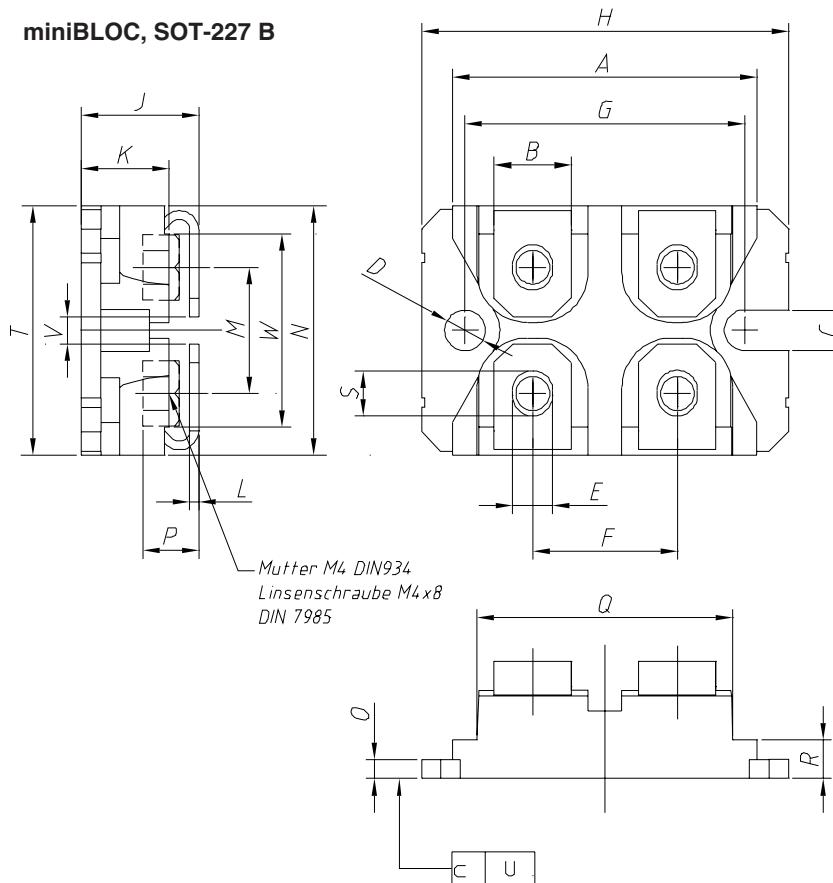
Symbol	Test Conditions	Maximum Ratings		
I _{TRMS}	T _{VJ} = T _{VJM}	234	A	
I _{TAV}	T _C = 80°C; (180° sine)	149	A	
I _{TSM}	T _{VJ} = 45°C; V _R = 0	2000 t = 10 ms (50 Hz), sine 2150 t = 8.3 ms (60 Hz), sine	A A	
	T _{VJ} = T _{VJM} V _R = 0	1750 t = 10 ms (50 Hz), sine 1850 t = 8.3 ms (60 Hz), sine	A A	
I ² t	T _{VJ} = 45°C V _R = 0	20000 t = 10 ms (50 Hz), sine 19400 t = 8.3 ms (60 Hz), sine	A ² s A ² s	
	T _{VJ} = T _{VJM} V _R = 0	15300 t = 10 ms (50 Hz), sine 14400 t = 8.3 ms (60 Hz), sine	A ² s A ² s	
(di/dt) _{cr}	T _{VJ} = T _{VJM} f = 50 Hz, t _p = 200 µs	repetitive, I _T = 150 A	100	A/µs
	V _D = 2/3 V _{DRM} I _G = 0.45 A di _G /dt = 0.45 A/µs	non repetitive, I _T = I _{TAVM}	500	A/µs
(dv/dt) _{cr}	T _{VJ} = T _{VJM} ; R _{GK} = ∞; method 1 (linear voltage rise)	V _{DR} = 2/3 V _{DRM}	1000	V/µs
P _{GM}	T _{VJ} = T _{VJM} I _T = I _{TAVM}	t _p = 30 µs t _p = 300 µs	10 5 0.5	W W W
P _{GAVM}				
V _{RGM}			10	V
T _{VJ}			-40...+150	°C
T _{VJM}			150	°C
T _{stg}			-40...+150	°C
V _{ISOL}	50/60 Hz, RMS;	I _{ISOL} ≤ 1 mA	2500	V~
M _d	Mounting torque (M4)		1.1 - 1.5 / 9 - 13 Nm/lb.in.	
	Terminal connection torque (M4)		1.1 - 1.5 / 9 - 13 Nm/lb.in.	
Weight	typ.		30	g

Data according to IEC 60747 and to a single thyristor/diode unless otherwise stated.

IXYS reserves the right to change limits, Conditions and dimensions.

Symbol	Test Conditions	Characteristic Values		
$I_{RRM/DRM}$	$T_{VJ} = 125^\circ\text{C}; V_R = V_{RRM}; V_D = V_{DRM}$	\leq	10	mA
V_T	$I_T = 80; T_{VJ} = 25^\circ\text{C}$	\leq	1.16	V
V_{TO}	For power-loss calculations only		0.8	V
r_T			3.8	$\text{m}\Omega$
V_{GT}	$V_D = 6 \text{ V}; T_{VJ} = 25^\circ\text{C}$	\leq	1.5	V
	$T_{VJ} = -40^\circ\text{C}$	\leq	1.6	V
I_{GT}	$V_D = 6 \text{ V}; T_{VJ} = 25^\circ\text{C}$	\leq	150	mA
	$T_{VJ} = -40^\circ\text{C}$	\leq	200	mA
V_{GD}	$T_{VJ} = T_{VJM}; V_D = \frac{2}{3} V_{DRM}$	\leq	0.2	V
I_{GD}		\leq	5	mA
I_L	$T_{VJ} = 25^\circ\text{C}; t_p = 10 \mu\text{s}$ $I_G = 0.45 \text{ A}; di_G/dt = 0.45 \text{ A}/\mu\text{s}$	\leq	450	mA
I_H	$T_{VJ} = 25^\circ\text{C}; V_D = 6 \text{ V}; R_{GK} = \infty$	\leq	200	mA
t_{gd}	$T_{VJ} = 25^\circ\text{C}; V_D = \frac{1}{2} V_{DRM}$ $I_G = 0.45 \text{ A}; di_G/dt = 0.45 \text{ A}/\mu\text{s}$	\leq	2	μs
t_q	$T_{VJ} = T_{VJM}; I_T = 20 \text{ A}, t_p = 200 \mu\text{s}; di/dt = -10 \text{ A}/\mu\text{s}$ $V_R = 100 \text{ V}; dv/dt = 15 \text{ V}/\mu\text{s}; V_D = \frac{2}{3} V_{DRM}$	typ.	150	μs
R_{thJC}	DC current		0.2	K/W
R_{thCH}	DC current	typ.	0.1	K/W
d_s	Creeping distance on surface		8	mm
d_A	Creepage distance in air		4	mm
a	Max. allowable acceleration		50	m/s^2

miniBLOC, SOT-227 B



M4 screws (4x) supplied

Dim.	Millimeter		Inches	
	Min.	Max.	Min.	Max.
A	31.50	31.88	1.240	1.255
B	7.80	8.20	0.307	0.323
C	4.09	4.29	0.161	0.169
D	4.09	4.29	0.161	0.169
E	4.09	4.29	0.161	0.169
F	14.91	15.11	0.587	0.595
G	30.12	30.30	1.186	1.193
H	37.80	38.23	1.489	1.505
J	11.68	12.22	0.460	0.481
K	8.92	9.60	0.351	0.378
L	0.76	0.84	0.030	0.033
M	12.60	12.85	0.496	0.506
N	25.15	25.42	0.990	1.001
O	1.98	2.13	0.078	0.084
P	4.95	5.97	0.195	0.235
Q	26.54	26.90	1.045	1.059
R	3.94	4.42	0.155	0.174
S	4.72	4.85	0.186	0.191
T	24.59	25.07	0.968	0.987
U	-0.05	0.1	-0.002	0.004
V	3.30	4.57	0.130	0.180
W	0.780	0.830	19.81	21.08

IXYS reserves the right to change limits, Conditions and dimensions.

451